

**LINEAR HALL-EFFECT IC****AH49E****General Description**

The AH49E is a small, versatile linear Hall-effect device that is operated by the magnetic field from a permanent magnet or an electromagnet. The output voltage is set by the supply voltage and varies in proportion to the strength of the magnetic field.

The integrated circuitry features low noise output, which makes it unnecessary to use external filtering. It also includes precision resistors to provide increased temperature stability and accuracy. The operating temperature range of these linear Hall sensors is -40°C to 85°C, appropriate for commercial, consumer and industrial applications.

The AH49E is available in standard TO-92S package.

**Features**

- Miniature Construction
- Power Consumption of 3.5mA at  $V_{CC}=5V$  for Energy Efficiency
- Single Current Sourcing Output
- Linear Output for Circuit Design Flexibility
- Low Noise Output Virtually Eliminates the Need for Filtering
- A Stable and Accurate Output
- Temperature Range of -40°C to 85°C
- Responds to Either Positive or Negative Gauss

**Applications**

- Current Sensing
- Motor Control
- Position Sensing
- Magnetic Code Reading
- Ferrous Metal Detector
- Vibration Sensing
- Liquid Level Sensing
- Weight Sensing

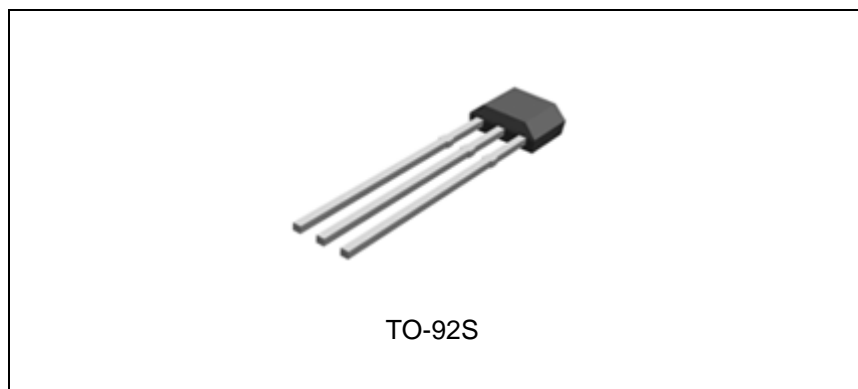


Figure 1. Package Type of AH49E

**LINEAR HALL-EFFECT IC**

**AH49E**

**Pin Configuration**

Z3 Package  
(TO-92S )

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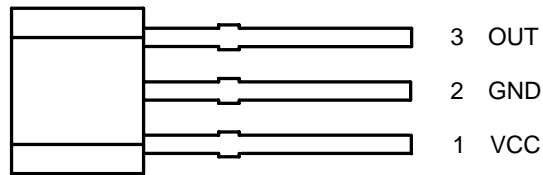


Figure 2. Pin Configuration of AH49E (Bottom View)

**Pin Description**

Pin Number	Pin Name	Function
1	VCC	Supply voltage
2	GND	Ground pin
3	OUT	Output

**LINEAR HALL-EFFECT IC**

**AH49E**

**Functional Block Diagram**

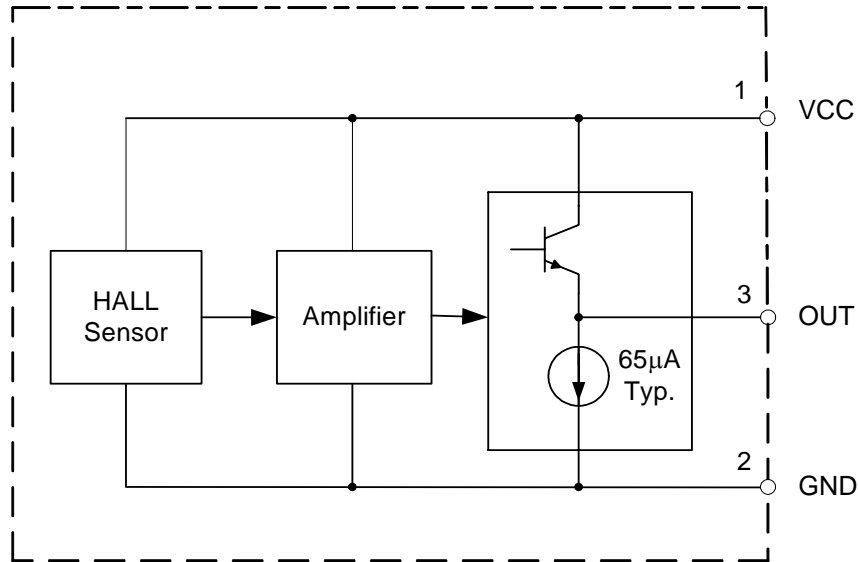
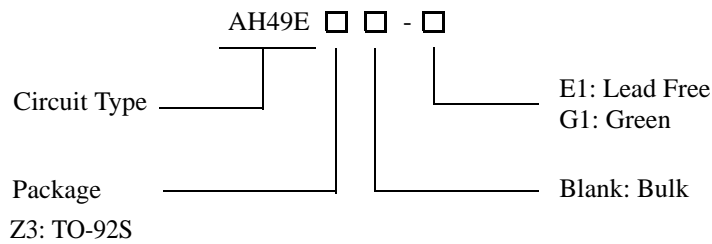


Figure 3. Functional Block Diagram of AH49E

**Ordering Information**



Package	Temperature Range	Part Number		Marking ID		Packing Type
		Lead Free	Green	Lead Free	Green	
TO-92S	-40 to 85°C	AH49EZ3-E1	AH49EZ3-G1	AH49E	AH49G	Bulk

BCD Semiconductor's Pb-free products, as designated with "E1" suffix in the part number, are RoHS compliant. Products with "G1" suffix are available in green package.

**LINEAR HALL-EFFECT IC****AH49E****Absolute Maximum Ratings (Note 1)**

Parameter	Symbol	Value	Unit
Supply Voltage	$V_{CC}$	8	V
Output Current	$I_O$	10	mA
Operating Temperature	$T_A$	-40 to 100	°C
Storage Temperature Range	$T_{STG}$	-50 to 150	°C
ESD (Human Body Model)		3000	V

Note 1: Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.

**Recommended Operating Conditions**

Parameter	Symbol	Min	Max	Unit
Supply Voltage	$V_{CC}$	3.0	6.5	V
Operating Temperature	$T_{OP}$	-40	85	°C

**LINEAR HALL-EFFECT IC****AH49E****Electrical Characteristics** $(V_{CC}=5V, T_A=25^{\circ}C, \text{ unless otherwise specified.})$ 

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Supply Current	$I_{CC}$			3.5	4.5	mA
Quiescent Output Voltage	$V_{NULL}$	@ B=0GS	2.25	2.5	2.75	V
Output Voltage Sensitivity		B=0GS to $\pm 1000$ GS	1.1	1.6	2.1	mV/GS
Output Voltage Span	$V_{OS}$		1.0 to $(V_{CC}-1.0)$	0.8 to $(V_{CC}-0.8)$		V
Output Resistor	$R_O$			60	120	$\Omega$
Magnetic Field Range	B		$\pm 650$	$\pm 1000$		GS
Linearity of Span				0.7		%
Output Noise		BW=10Hz to 10kHz		90		$\mu V$

**Transfer Characteristics ( $V_{CC}=5V$ )**

When there is no outside magnetic field ( $B=0GS$ ), the quiescent output voltage is one-half the supply voltage in general. If a south magnetic pole approaches to the front face (the side with marking ID) of the Halleffect sensor, the circuit will drive the output voltage higher. Contrary, a north magnetic pole will drive the output voltage lower. The variations of voltage level up or down are symmetrical.

Greatest magnetic sensitivity is obtained with a supply voltage of 6V, but at the cost of increased supply current and a slight loss of output symmetry. So, it is not recommended to work in such condition unless the output voltage magnitude is a main issue. The output signal can be capacitively coupled to an amplifier for boosting further if the changing frequency of the magnetic field is high.

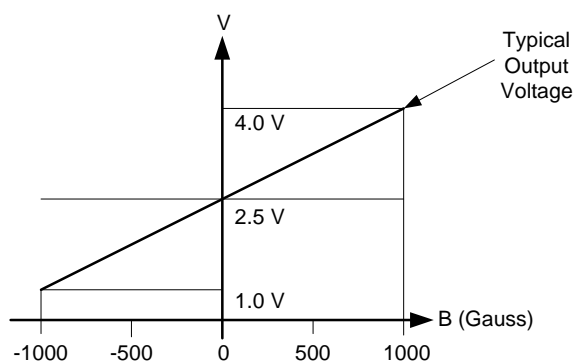


Figure 4. The Transfer Characteristics of AH49E



**LINEAR HALL-EFFECT IC**

**AH49E**

**Typical Performance Characteristics**

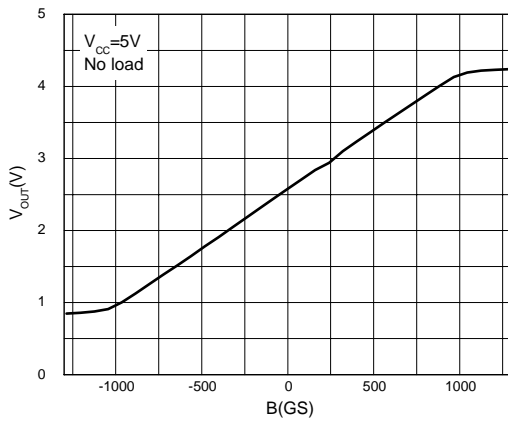


Figure 5. Output Voltage vs. Magnetic Field

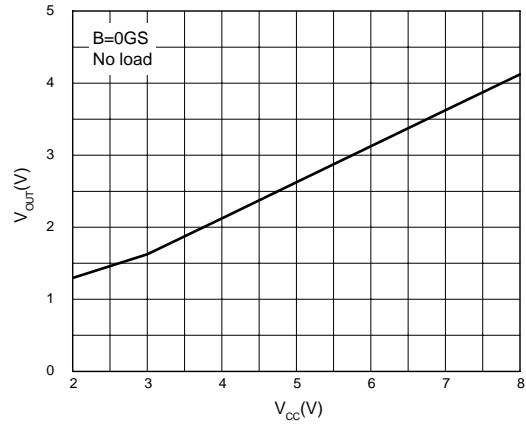


Figure 6. Output Voltage vs. Supply Voltage

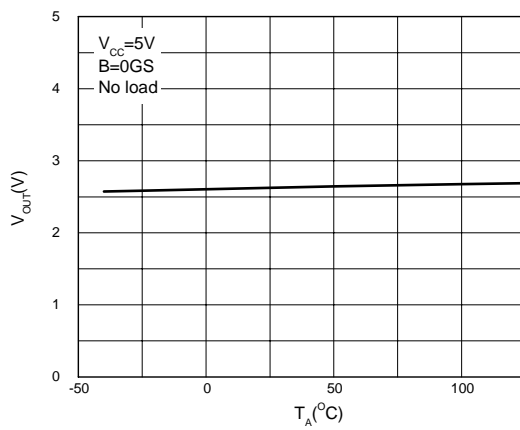


Figure 7. Output Voltage vs. Ambient Temperature



**LINEAR HALL-EFFECT IC**

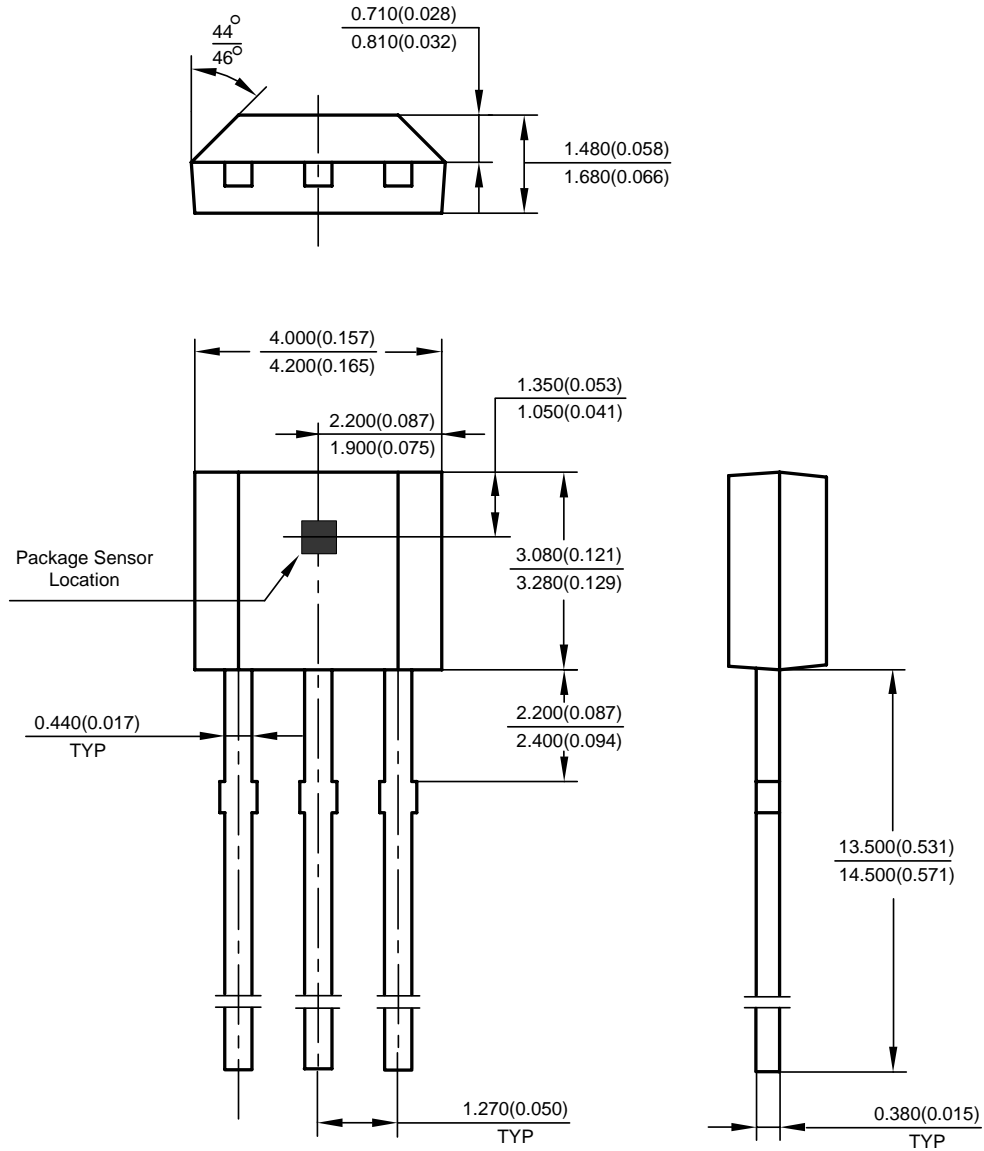
**AH49E**

**Mechanical Dimensions**

**TO-92S**

**Unit: mm(inch)**

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